

Electronic Supplementary Information

A General Strategy for the Functionalization of Two-dimensional Metal Dichalcogenides

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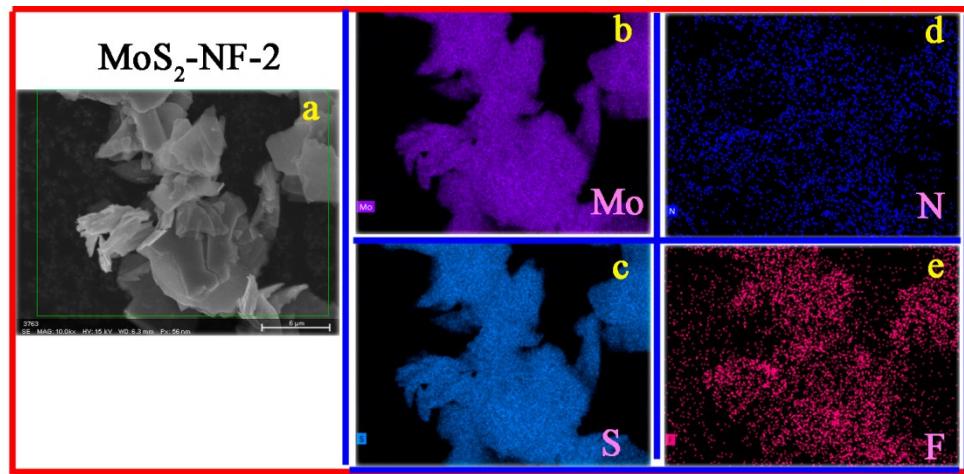


Figure S1 SEM (a) and EDX-Mapping (b-e) of MoS₂-NF-2

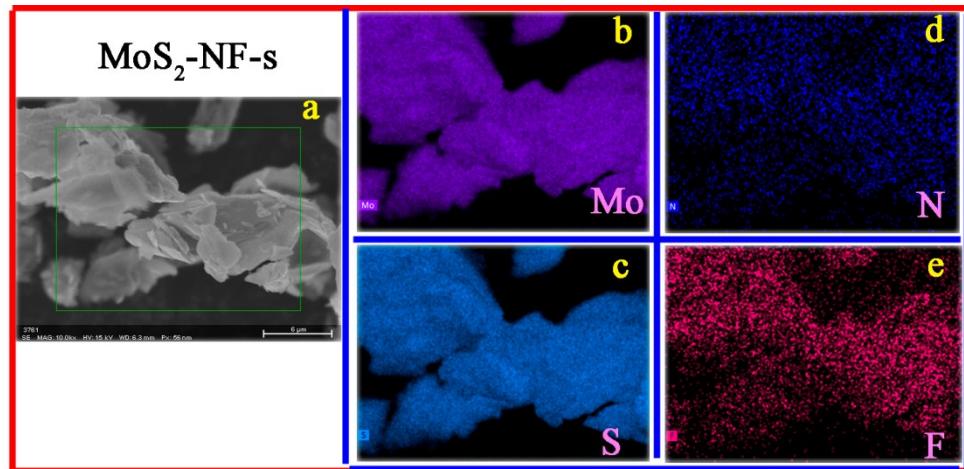


Figure S2 SEM (a) and EDX-Mapping (b-e) of MoS₂-NF-s

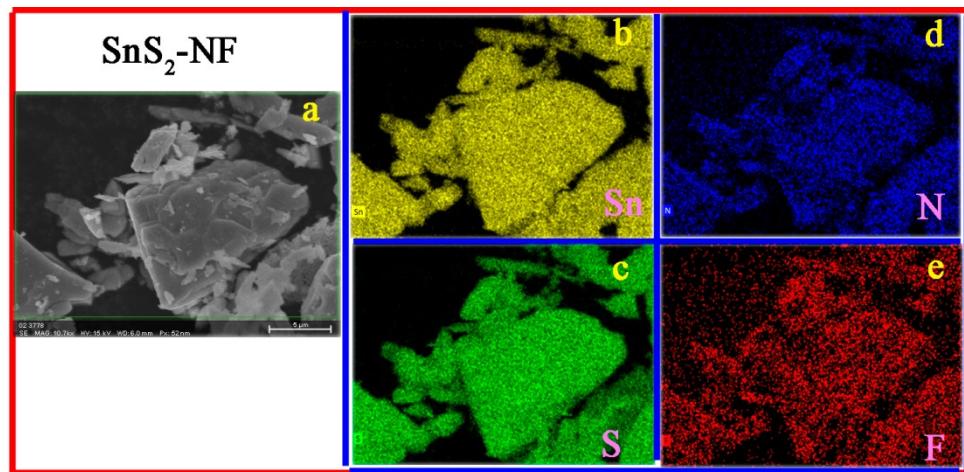


Figure S3 SEM (a) and EDX-Mapping (b-e) of SnS₂-NF

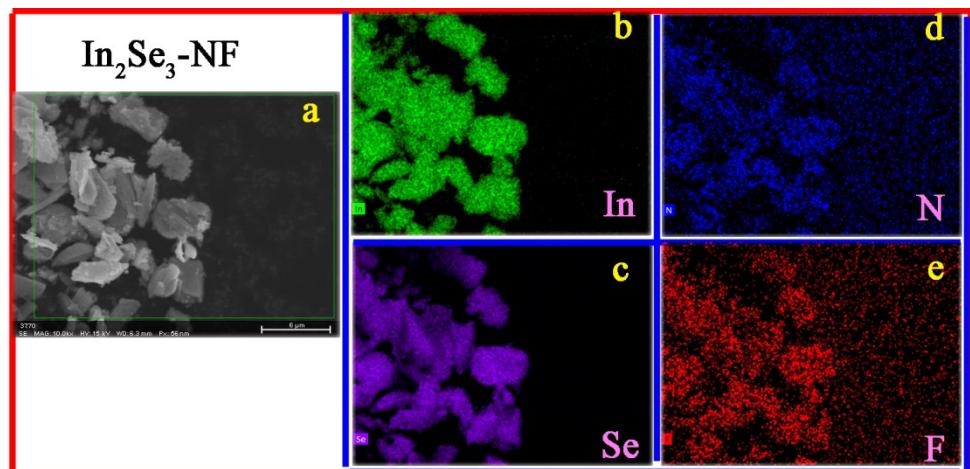


Figure S4 SEM (a) and EDX-Mapping (b-e) of In_2Se_3 -NF

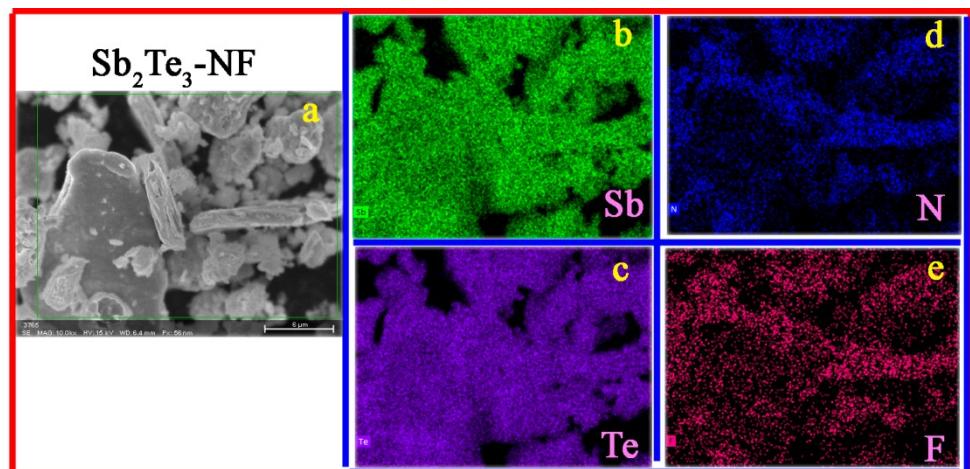


Figure S5 SEM (a) and EDX-Mapping (b-e) of Sb_2Te_3 -NF

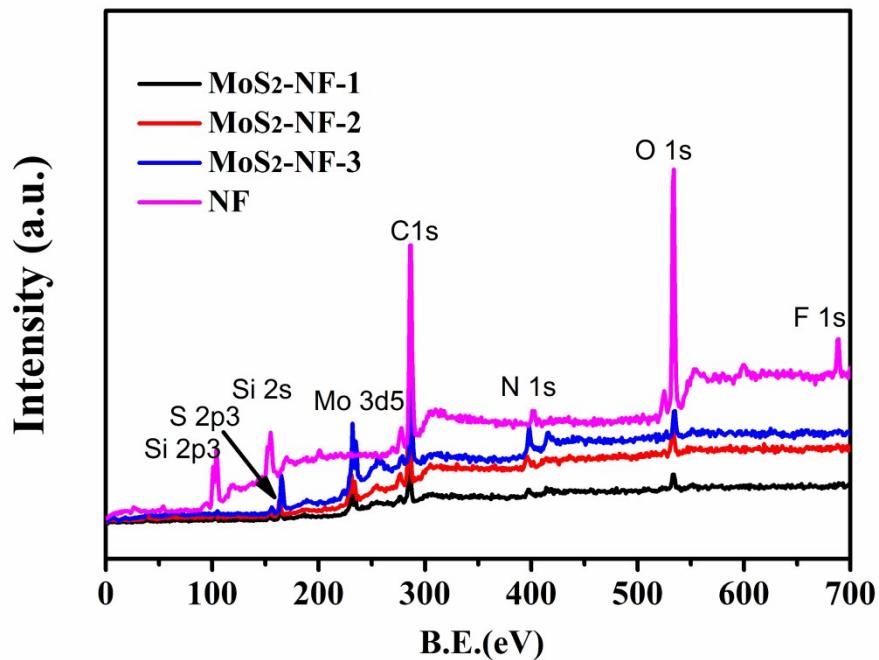


Figure S6 XPS survey spectra of MoS₂-NFs and NF

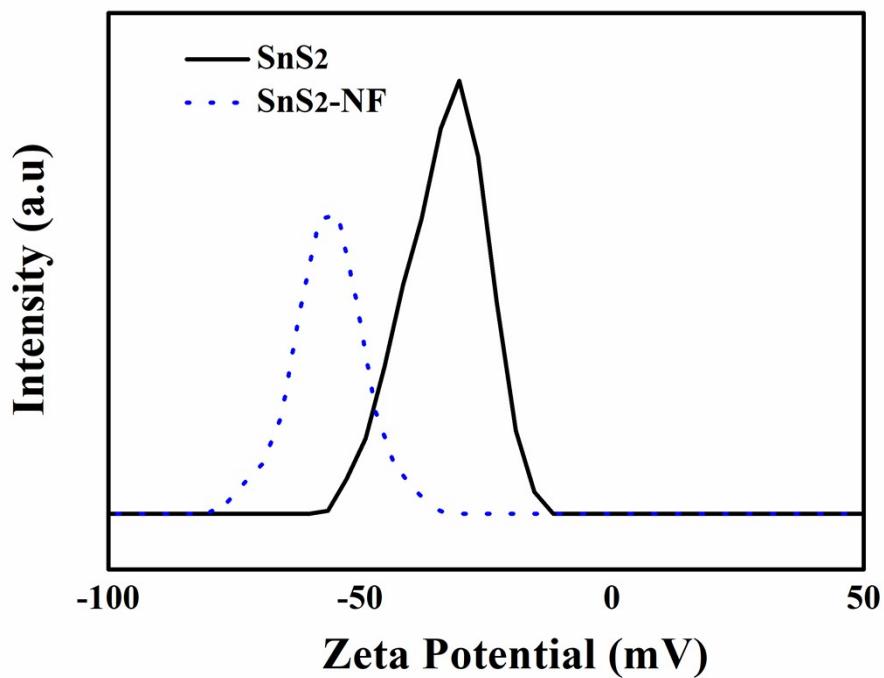


Figure S7 Zeta potential of pristine and functionalized SnS₂ nanosheets

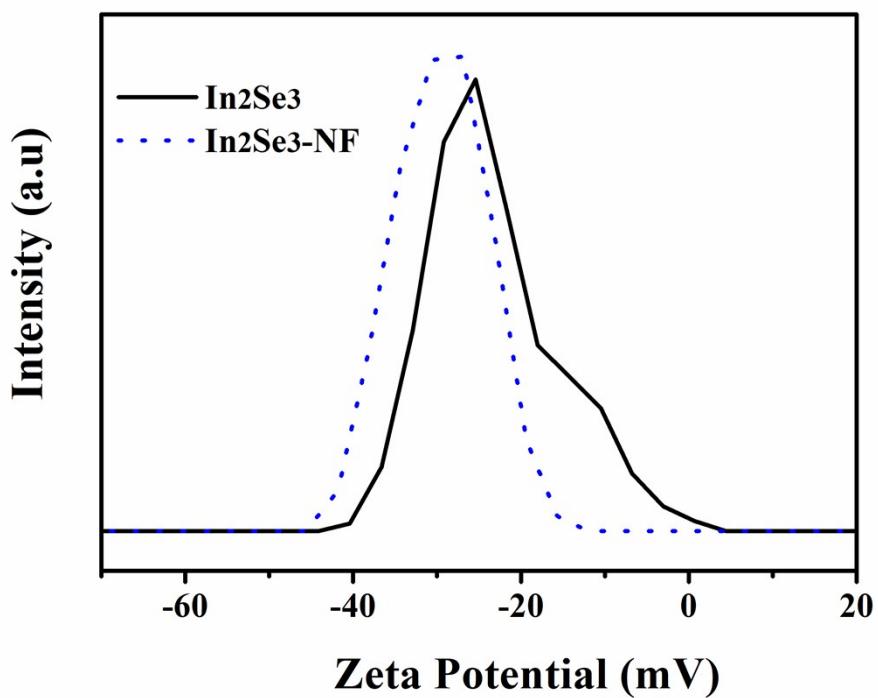


Figure S8 Zeta potential of pristine and functionalized In_2Se_3 nanosheets

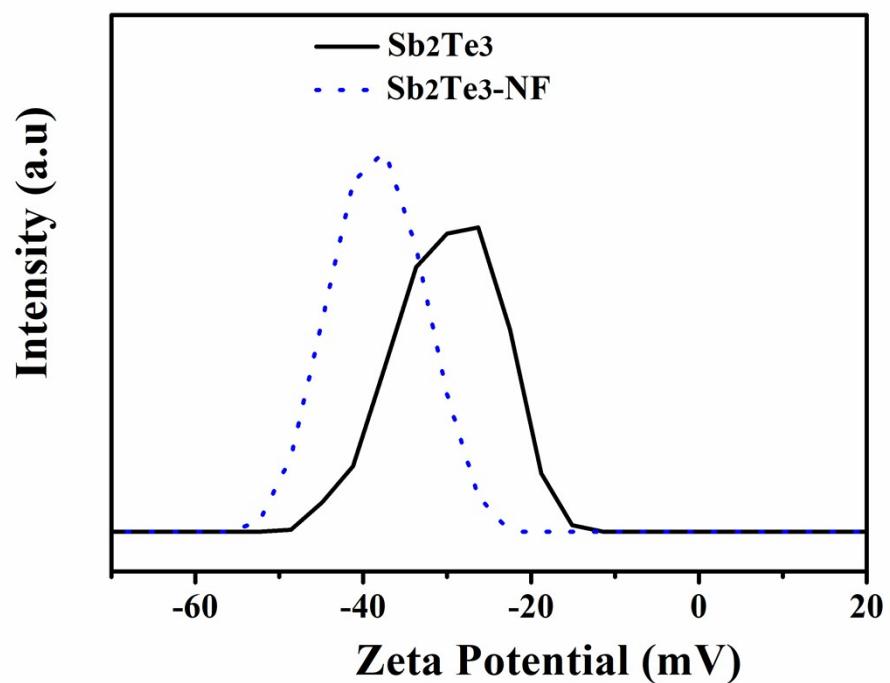


Figure S9 Zeta potential of pristine and functionalized Sb_2Te_3 nanosheets

Table S1 Summary of the position and FWHM of E_{2G}¹ and A_{1G} of original and functionalized MoS₂.

	Peak position (cm ⁻¹)		FWHM (cm ⁻¹)	
	E _{2G} ¹	A _{1G}	E _{2G} ¹	A _{1G}
MoS ₂	379.2	404.3	9.2	9.4
MoS ₂ -NF-1	376.6	403.4	9.8	10.1
MoS ₂ -NF-2	376.1	402.9	10.2	10.5
MoS ₂ -NF-3	375.2	402.3	11.1	10.7